

Computational study of (111) epitaxially strained ferroelectric perovskites BaTiO₃ and PbTiO₃

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The phase transition behavior of PbTiO₃ and BaTiO₃ under (111) epitaxial strain is investigated using density-functional theory calculations. From tensile strains of +0.015 to compressive strains of -0.015, PbTiO₃ undergoes phase transitions from $C2$ through two Cm phases and then to $R3m$. The total polarization is found to be almost independent of strain. For the same range of strains BaTiO₃ undergoes phase transitions from a single Cm phase, through $R3m$ and then to $R\bar{3}m$. In this case the application of compressive strain inhibits and then completely suppresses the polarization on transition to the nonpolar $R\bar{3}m$ phase.

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I. INTRODUCTION

Perovskite materials have been extensively studied due to their numerous structures and properties.¹ At room temperature bulk BaTiO₃ and PbTiO₃ are ferroelectric with spontaneous polarizations of around 25 μCcm^{-2} and 80 μCcm^{-2} , respectively. Epitaxial strain can have a considerable effect on the structural and electrical properties of perovskite thin films.²⁻⁵ The properties of thin films can, therefore, be fine-tuned by growing the films epitaxially and coherently on a substrate with a desired lattice constant.

The effect of strain has already been studied for perovskite thin films oriented in the (001) direction on a cubic substrate.⁵⁻⁹ (111) epitaxial films have different symmetries than (001) films and, therefore, the behavior will also be different. The temperature-strain phase diagram of PbTiO₃ (111) films has been modeled using a thermodynamic mean-field approach.¹⁰ For room temperature and below, it was predicted that the film should have $3m$ point symmetry for compressive strains and two different m symmetry phases for tensile strains, with first-order transitions between the phases. In this paper we investigate the stability of various phases of (111) films of PbTiO₃ and BaTiO₃ under epitaxial strain at $T=0$ K using density-functional theory (DFT) calculations. We show that the zero-temperature phases of PbTiO₃ mostly agree with the higher-temperature results of Ref. 10. BaTiO₃ exhibits a qualitatively different behavior from PbTiO₃ and, surprisingly, the application of compressive strain is found to suppress the polarization.

II. METHOD

The parent space group for a (111) epitaxially strained perovskite film is $R\bar{3}m$. In this work we used 15-atom unit cells, but only considered symmetries compatible with a five-atom primitive cell. Periodic boundary conditions were used, and the effect of the substrate is implicitly included by constraining the \hat{a} and \hat{b} lattice parameters to be (1,0,0) and $(-\frac{1}{2}, \frac{\sqrt{3}}{2}, 0)$ and scaling both lattice vectors with mismatch strain. We have not included a surface as a ferroelectric field in vacuum gives rise to a depolarizing field, which suppresses polarization. This approach allows us to separate the

effect of epitaxial strain from surface effects.

The ISOTROPY code¹¹ and the Bilbao Crystallographic Server¹² were used to find space groups compatible with a perovskite (111) film. Figure 1 shows the various subgroups of $R\bar{3}m$ with a possible five-atom primitive cell and their symmetry relations. The monoclinic geometry of the substrate implies that $P\bar{1}$ will actually have a higher $C2/m$ symmetry, and $R\bar{3}$ actually has the higher $R\bar{3}m$ symmetry for perovskites as the mirror-plane breaking Wyckoff positions are not occupied. Therefore, eight possible space groups exist and are shown in Table I. The possible unstrained bulk symmetries that reduce to these space groups when (111) strain is applied are listed in Table II, with the Cm phase divided into three types as shown in Fig. 2.

For the (111) perovskite, fewer polarization directions are allowed than in the (001) case. The nonpolar $R32$ and $C2/m$ space groups are not expected to be seen in the (111) perovskite,¹⁰ and they have not been considered. For displacements strictly perpendicular to the plane, the polarization $P_3\hat{z}$ and the space group $R3m$ are obtained. $R3m$ is predicted to be stable for compressive strains in PbTiO₃.¹⁰ $R3$ is a subgroup of $R3m$ that has polarization in the same direction but additional displacements of atoms to break the mirror plane.

For displacements parallel to a lattice vector in the plane, the polarization $P_1\hat{a}$ and the space group $C2$ are obtained. The stability of such a PbTiO₃ phase is considered uncertain in Ref. 10, as it depends on the selection of model parameters.

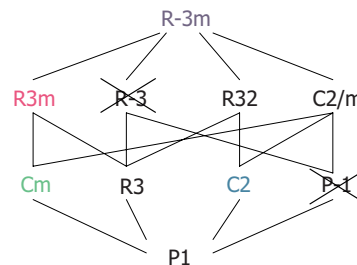


FIG. 1. (Color online) The subgroups of $R\bar{3}m$ with a possible five-atom primitive cell. Crossed symmetries are not present in (111) epitaxial perovskite.

TABLE I. Description of the nonpolar and polar (111) epitaxial perovskite symmetry groups with a possible five-atom primitive cell. Vectors are given in the standard rectangular Cartesian basis ($\hat{a}, \frac{\hat{a}+2\hat{b}}{\sqrt{5}}, \hat{z}$). N_P is the number of free parameters in atomic fractional coordinates when we restrict the primitive cell to five atoms, although the symmetries marked with * would allow a 15-atom primitive cell, with more free parameters in fractional coordinates.

Space group	c axis	Polarization	N_P
166	$R\bar{3}m$	0	0
155	$R32$	0	1
12	$C2/m$	$c_1\hat{a}+c_3\hat{z}$	0*
160	$R3m$	$P_3\hat{z}$	3
146	$R3$	$P_3\hat{z}$	4
8	Cm	$P_2\frac{\hat{a}+2\hat{b}}{\sqrt{5}}+P_3\hat{z}$	7*
5	$C2$	$P_3\hat{z}$	5*
1	$P1$	$P_1\hat{a}+P_3\hat{z}$	12*

For displacements parallel to $\hat{a}+2\hat{b}$ (or, equivalently, $\hat{a}-\hat{b}$ or $\hat{a}+2\hat{b}$) in the plane, the space group Cm is obtained, in which the polarization is only constrained to lie in a mirror plane perpendicular to the epitaxial plane. According to the Landau theory, Cm is stable for tensile strains in PbTiO_3 (Ref. 10) (when using the parameters from Ref. 13), and the transition $Cm \rightarrow R3m$ is first order. Due to symmetry considerations, transition $Cm \rightarrow C2$ also has to be first order.

Within the monoclinic Cm space group, there are three inequivalent possible energy minima, with isotropic phase transitions between them. They correspond to the bulk space groups $R3m$, $Amm2$, and $P4mm$ and pseudocubic bulk polarization directions (111), (110), and (100), respectively.¹⁰ In Ref. 14, the stability of the monoclinic phase in bulk is studied with high-order Devonshire theory, and possible monoclinic M_A and M_B phases (along with M_C , which would have Pm symmetry that is not possible in a (111) biaxially strained perovskite) originate in the eighth-order expansion of the thermodynamic potential. Our $Amm2$ minimum corresponds to M_B and $P4mm$ minimum to M_A , as displayed in Fig. 2.

Finally, a triclinic phase with no symmetry constraints ($P1$) would require twelfth-order terms in Ref. 14 and is predicted to be unlikely in the bulk. No such phase is con-

TABLE II. Considered strained symmetries and bulk symmetries that reduce to them when (111) strain is applied.

Strained	Unstrained
$R\bar{3}m$	$Pm\bar{3}m$
$R3m$	$R3m$
$R3$	$R3$
$Cm (M_A)$	Cm and $P4mm$
$Cm (M_B)$	Cm and $Amm2$
Cm (between M_A and M_B)	$R3m$
$C2$	$Amm2$
$P1$	$P1$ and Pm

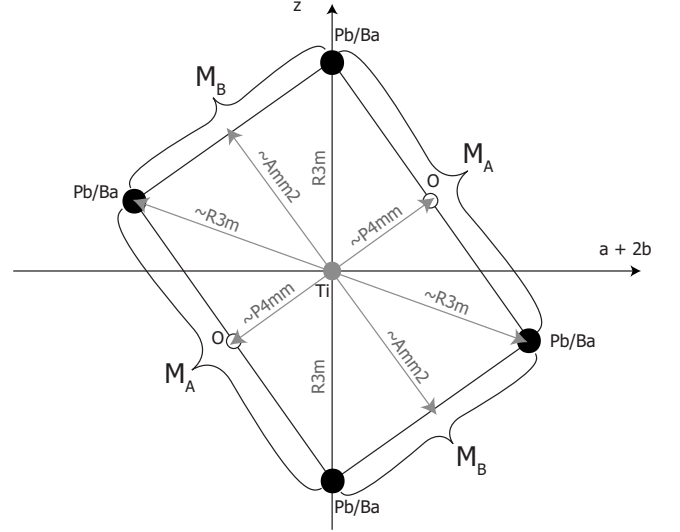


FIG. 2. Possible polarization directions in the mirror plane of the Cm symmetry. The tilde denotes the presence of symmetry at zero strain.

sidered in Ref. 10 either, and it is left outside the present study.

In a strained film, there are nonzero stresses σ_1 and σ_2 (in the standard Cartesian axes) in the epitaxial direction. Therefore, the thermodynamic potential that is minimized is the elastic enthalpy

$$H = U + e_m(\sigma_1 + \sigma_2), \quad (1)$$

where U is the internal energy and e_m is the in-plane strain relative to the relaxed lattice constant of the phase in question. The phase with lowest elastic enthalpy at given mismatch strain is the equilibrium state of a coherent epitaxial single-domain film. The internal energies and stresses for each phase as a function of strain are obtained from DFT calculations after relaxing atomic positions and unit cell parameters within the constraints of Table I.

The DFT calculations were performed using the vienna *ab initio* simulation package (VASP).^{15,16} The core states were represented using the projector augmented wave (PAW) method^{17,18} and the semicore Pb, Ba, and Ti were treated as valence electrons. The plane-wave cutoff energy was 700 eV. The exchange and correlation energy was described using the local-density approximation (LDA). The polarization of the phases was calculated using Berry phase formalism.^{19,20}

The hexagonal (monoclinic for Cm) conventional cell contained 15 atoms and consisted of three identical five-atom primitive cells. A Γ -centered Brillouin zone mesh of $6 \times 6 \times 4$ was used.

Ionic relaxations were performed for various c/a ratios (for all space groups) and c -axis tilt angles (for Cm) to obtain the optimal cell shape and volume for each fixed in-plane strain. Relaxations were stopped when the Hellmann-Feynman forces on the atoms were below 0.01 eV/Å.

III. RESULTS

The relaxed DFT bulk cubic lattice values were 3.895 Å for PbTiO_3 and 3.955 Å for BaTiO_3 , and they were used as

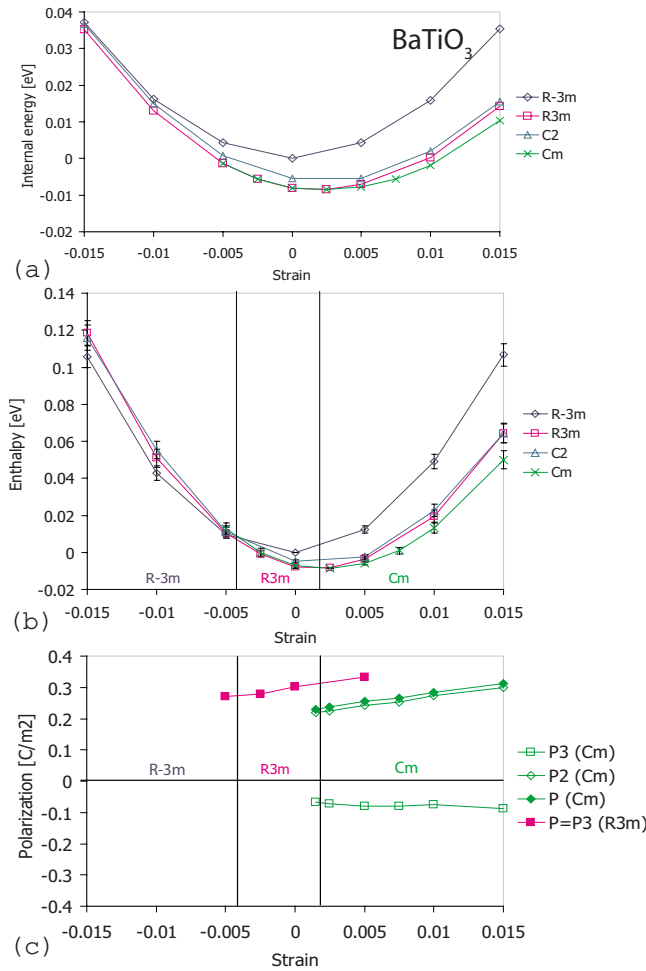


FIG. 3. (Color online) (a) The internal energies (per five-atom primitive cell) given by VASP for considered phases of BaTiO₃. (b) Elastic enthalpies (per five-atom primitive cell) as given by Eq. (1) for considered phases of BaTiO₃. The error bars indicate approximate error in enthalpy due to stress inaccuracy in VASP and discretization in strain, c/a ratio, and c -axis angle. The vertical lines denote approximate points of phase transition. (c) Polarization of the BaTiO₃ phase with lowest elastic enthalpy at each strain. P is the total polarization and P_1 , P_2 , and P_3 are the polarization components in the \hat{a} , $\frac{\hat{a}+2\hat{b}}{\sqrt{5}}$, and \hat{z} directions, respectively.

the unstrained lattice constants. The calculated c/a ratios in the bulk tetragonal phase were 1.04 for PbTiO₃ and 1.003 for BaTiO₃, and corresponding polarizations in the bulk tetragonal phase were 0.77 Cm⁻² for PbTiO₃ and 0.21 Cm⁻² for BaTiO₃. As expected, these values are somewhat smaller than the experimental values, which is typical of the LDA approximation. The experimental cubic lattice constants are 3.97 Å (Ref. 21) and 4.00 Å,²² the tetragonal c/a ratios are 1.07 and 1.01 and the polarizations are 0.80 Cm⁻² (Ref. 23) and 0.26 Cm⁻²,²⁴ for PbTiO₃ and BaTiO₃, respectively.

The internal energies and corresponding elastic enthalpies for the considered epitaxial phases, with error estimates, are displayed as a function of strain in Fig. 3 for BaTiO₃ and Fig. 4 for PbTiO₃. In the enthalpy curves, the energetically favored phases are denoted. The error in enthalpy is proportional to relative strain squared. For PbTiO₃, two separate

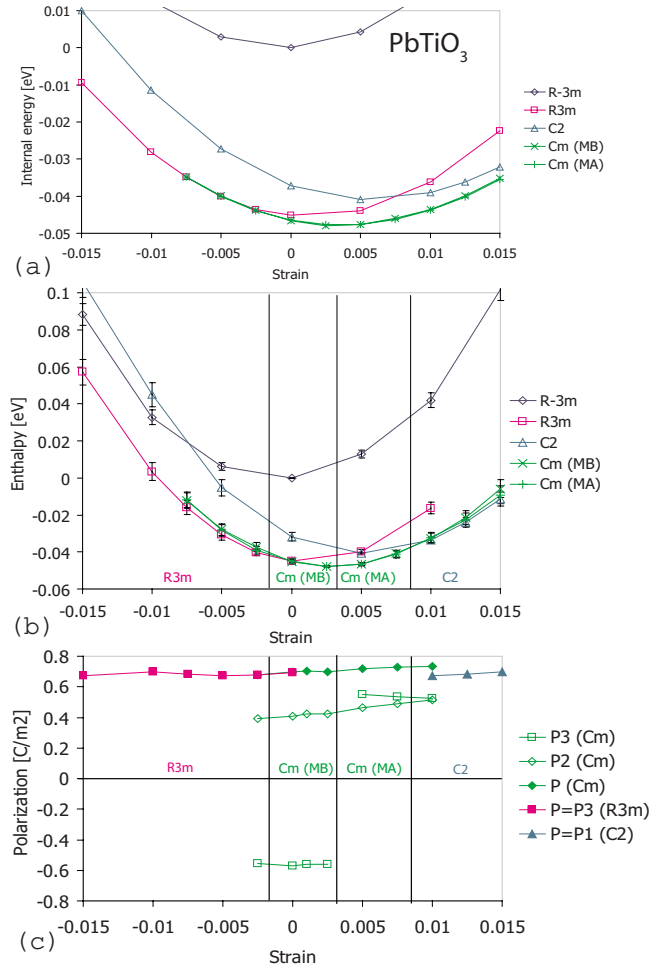


FIG. 4. (Color online) (a) The internal energies (per five-atom primitive cell) given by VASP for considered phases of PbTiO₃. (b) Elastic enthalpies (per five-atom primitive cell) as given by Eq. (1) for considered phases of PbTiO₃. The error bars indicate approximate error in enthalpy due to stress inaccuracy in VASP and discretization in strain, c/a ratio, and c -axis angle. The vertical lines denote approximate points of phase transition. (c) Polarization of the PbTiO₃ phase with lowest elastic enthalpy at each strain. P is the total polarization and P_1 , P_2 , and P_3 are the polarization components in the \hat{a} , $\frac{\hat{a}+2\hat{b}}{\sqrt{5}}$, and \hat{z} directions, respectively.

but almost identical energy curves for the Cm phases were obtained, corresponding to different energy minima within the same symmetry, by relaxing the unit cell starting from three different starting configurations. For the strains considered, $R3$ was found to relax into the $R3m$ symmetry for both PbTiO₃ and BaTiO₃, so no separate $R3$ curve is plotted.

In-plane (P_1 and P_2), perpendicular to plane (P_3), and total (P) polarization of the perovskites as a function of strain are displayed in Fig. 3 for BaTiO₃ and Fig. 4 for PbTiO₃. The components displayed are strictly from the phase of lowest enthalpy for each strain as denoted, although the error due to discretization in strain, c/a ratio, and c -axis angle makes the preferred phase uncertain at large compressive or tensile strains and between the two PbTiO₃ Cm phases.

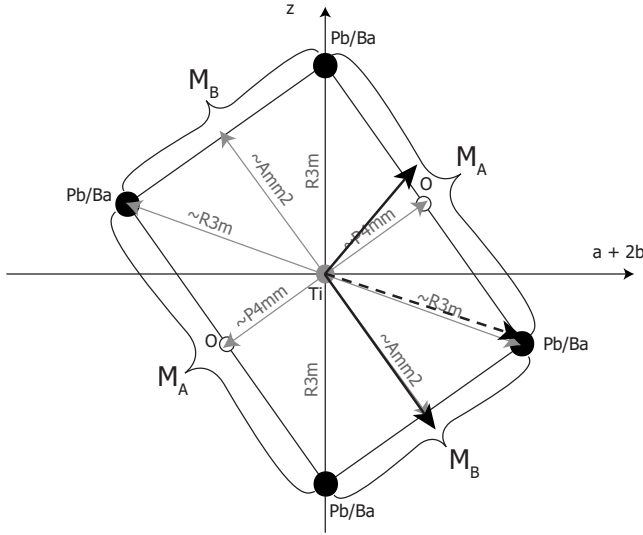


FIG. 5. Approximate polarization directions in the mirror plane of the C_m symmetry. BaTiO_3 adopts a single energy minimum: The dashed arrow indicates polarization of BaTiO_3 at tensile strain 0.0025. PbTiO_3 adopts two energy minima: The black arrows indicate polarization of PbTiO_3 M_B and M_A phases at tensile strains 0 and 0.005, respectively. The tilde means symmetry direction at zero strain.

A. BaTiO_3

For BaTiO_3 , only a single energy curve for the C_m phase could be obtained, with relaxation to a single energy minimum instead of transitions between them. This energy minimum most closely corresponds to a nearly $R3m$ structure, with polarization toward a Ba atom as indicated in Fig. 5, and virtually no rotation of polarization with increasing strain. The result is in accordance with the known tendency of BaTiO_3 to adopt the rhombohedral phase in the bulk. The transition $C_m \rightarrow R3m$ is seen to be first order (with polarization vector as the order parameter), as predicted by an extension of Devonshire theory.¹⁴ The other BaTiO_3 transition, ferroelectric-to-paraelectric ($R3m \rightarrow R\bar{3}m$) transition induced by compressive strain, is similarly seen to be first order. Although the polarized $R3m$ phase has a lower internal energy than the $R\bar{3}m$ phase, the lower stresses observed in the paraelectric phase make it favored at compressive strains when elastic enthalpy is considered.

B. PbTiO_3

In PbTiO_3 , the C_m polarization direction at tensile strains is dominated by the tendency to adopt a nearly $P4mm$ (M_A) or $Amm2$ (M_B) structure. These polarization directions in the mirror plane of the C_m phase are sketched and labeled in Fig. 5. No relaxation to a nearly $R3m$ structure, as in BaTiO_3 , is observed. Therefore, when the tensile strain is increased, a transition from M_B to M_A structure, with consequent flipping of one polarization component, is seen in Fig. 4. Such a strain-induced transition is indeed predicted for (111) PbTiO_3 in Ref. 10, and all the PbTiO_3 transitions are first order (polarization vector changes discontinuously) as predicted.

TABLE III. Calculated LDA band gaps for lowest-enthalpy phases at different in-plane strains of (111) epitaxial perovskite. In the pseudocubic Brillouin zone, the band gaps are indirect Γ - X and Γ - R gaps for PbTiO_3 and BaTiO_3 , respectively. Energies are in eV.

Strain	-0.01	0	0.01	Cubic	Measured bulk (RT)
PbTiO_3	1.84	1.77	1.71	1.48	3.4 ^a
BaTiO_3	1.72	2.05	2.11	1.72	3.0 ^b

^aReference 25.

^bReference 26.

This is in apparent contradiction with the fact that bulk PbTiO_3 is known to adopt $P4mm$ symmetry when unstrained; however, the unstrained (111) epitaxial case is different from the bulk. Even at zero strain, the (111) substrate inhibits the tetragonal elongation of the unit cell required for the $P4mm$ phase to be stable, and the $Amm2$ (M_B) geometry is adopted instead. When increasing tensile strain, an M_A structure closer to $P4mm$ is adopted, as it allows the polarization to align more parallel to the strain.

The single enthalpy differences between the PbTiO_3 C_m structures are smaller than possible errors in enthalpy, but the enthalpy curves of Fig. 4 as a whole display slight differences between the M_A and M_B structures. Polarization in the two phases rotates very little in the narrow strain range where each phase is stable, though it would rotate significantly more if C_m were stable at larger tensile strains. At large tensile strains, although the C_m phase still has the lowest internal energy, the $C2$ phase is favored in terms of elastic enthalpy, as its relaxed lattice constant is higher than that of the C_m phase. Therefore, large tensile strain (around 1%) causes PbTiO_3 polarization to align along a lattice vector in the (111) plane; the structure is similar to the $Amm2$ phase in bulk, but with lower symmetry due to strain.

C. Band gaps

Finally, the LDA band gaps for the favored phases were calculated, to compare with LDA band gaps of cubic BaTiO_3 and PbTiO_3 . While LDA seriously underestimates band gaps, any strain-induced changes in the LDA band gaps may indicate widening or closing of the band gap due to strain. The results for the two perovskites are shown in Table III. The band structures and gaps are very similar to calculations on cubic perovskites,¹ and the Γ - X type of indirect gap in PbTiO_3 agrees with optical measurements of the room temperature bulk.²⁵ It can be seen that all nonpseudocubic phases have the effect of widening the gap compared to the calculated bulk cubic values, but there are no clear trends or major changes in the size of the band gap.

IV. DISCUSSION AND CONCLUSIONS

BaTiO_3 has C_m symmetry for large tensile strains and undergoes a phase transition to the $R3m$ phase at a strain of ≈ 0.002 . In both $R3m$ and C_m phases, the total polarization decreases approximately linearly as compressive strain is in-

creased. The most surprising result is the adoption of the nonpolar $R\bar{3}m$ phase below a strain of -0.004 . Therefore, compressive strain appears to inhibit and, finally, suppress ferroelectricity in (111) epitaxial BaTiO_3 . There are observations of such inhibition of remanent polarization in (111) epitaxial BaTiO_3 on LaNiO_3 -coated SrTiO_3 substrates²⁷ which would inflict compressive strain due to lattice mismatch, and in (111) $\text{BaTiO}_3/\text{SrTiO}_3$ superlattices.²⁸ However, it is also possible that a cell-doubling transition may occur, as only phases with a five-atom primitive cell were considered in this study.

Both perovskites have a strain region in which the $R\bar{3}m$ phase is stable and undergoes a first-order phase transition into the Cm phase when tensile strain is increased. The geometry of the Cm phase differs in the two perovskites, with a single minimum in BaTiO_3 and first-order isomorphic transition between two Cm phases in PbTiO_3 , with switching of the vertical polarization component. Such a transition was predicted in Ref. 10 although their phase diagram has a lower limit of -50°C and our first-principles calculations are valid at absolute zero. Another indication of this isomorphic transition is the observation of inversion of the vertical polarization in (111) PZT thin-film capacitors.²⁹ However, the strain in these thin-film capacitors is unknown.

In PbTiO_3 it is observed that as tensile strain grows, the $C2$ phase (with in-plane polarization) is adopted. Indeed, in Ref. 10 it is noted that such a phase could be stable instead of Cm , depending on the parameters used in the thermodynamic expansion. The total polarization of the stable phases of PbTiO_3 is observed to be almost independent of the applied strain. The direction of polarization, but not its magnitude, changes with (111) strain. Such a suppressed dependence of polarization on strain has been observed earlier in tetragonal (100) epitaxial $\text{PbZr}_{0.2}\text{Ti}_{0.8}\text{O}_3$ (PZT).³⁰ This was proposed to be due to the fact that the polarization of PZT is already large so the Pb ions are less sensitive to strain.³⁰ Since PbTiO_3 also has large atomic displacements it is likely to exhibit similar behavior to PZT.

The magnitudes of the calculated polarization are similar to those observed in the (100) epitaxial case for both perovskites,^{2,30} apart from our predicted suppression of BaTiO_3 polarization at compressive strain. Such suppression

under compressive strain has also been observed in (111) epitaxial BaTiO_3 ,^{27,28} with remanent polarization of only $0.1 \mu\text{Ccm}^{-2}$, opposed to $19.9 \mu\text{Ccm}^{-2}$ in the (100) case.²⁷ We are aware of no other reports on the magnitude of observed polarization in (111) epitaxial PbTiO_3 or BaTiO_3 .

The calculations presented here do have a number of limitations. First, the calculations give the internal energy at zero temperature. A full strain-temperature phase diagram of a (111) epitaxial perovskite could be produced by parametrizing an effective Hamiltonian model using first-principles results.^{5,9} Second, the effect of the surface has not been considered. Third, no cell-doubling phases, such as octahedral rotations or other complex structures that require larger than five-atom primitive cells, were considered, even though they may appear in perovskites in the stress regime considered here (e.g., Ref. 31). The stability of the phases suggested here could be confirmed, for example, by calculating phonon modes. This was left beyond the scope of this study due to the large computational requirements of investigating each phase under various strains. Fourth, ionic zero-point motion has a significant effect on the adopted phases as a function of pressure at low temperatures, and it could significantly alter the phase diagram.³² For BaTiO_3 in particular, the shallowness of the potential wells makes this effect considerable up to several hundred kelvin in the GPa pressure range,³² corresponding to strains considered here. This effect could be taken into account by an effective Hamiltonian, if a path-integral quantum Monte Carlo technique, instead of classical Monte Carlo, was used in thermodynamic simulations. A final point to be noted is that while LDA is known to well reproduce many perovskite properties, the fact that it somewhat underestimates atomic displacements when compared to experiments could have an effect on the energetics of the various phases, as their elastic enthalpies are very close to each other.

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